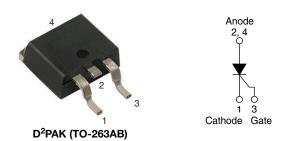
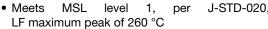


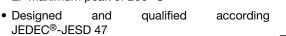
Thyristor Surface Mount, Phase Control SCR, 16 A



PRIMARY CHARACTERISTICS							
I _{T(AV)} 16 A							
V_{DRM}/V_{RRM}	1600 V						
V_{TM}	1.25 V						
I _{GT}	45 mA						
T_J	-40 °C to +125 °C						
Package	D ² PAK (TO-263AB)						
Circuit configuration	Single SCR						

FEATURES





 Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>







APPLICATIONS

- Input rectification (soft start)
- Vishay input diodes, switches and output rectifiers which are available in identical package outlines

DESCRIPTION

The VS-25TTS16SPbF of silicon controlled rectifiers is specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

OUTPUT CURRENT IN TYPICAL APPLICATIONS								
APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE U								
NEMA FR-4 or G10 glass fabric-based epoxy with 4 oz. (140 μm) copper	3.5	5.5						
Aluminum IMS, R _{thCA} = 15 °C/W	8.5	13.5	A					
Aluminum IMS with heatsink, R _{thCA} = 5 °C/W	16.5	25.0						

Note

• $T_A = 55$ °C, $T_J = 125$ °C, footprint 300 mm²

MAJOR RATINGS AND CHARACTERISTICS									
PARAMETER	TEST CONDITIONS	VALUES	UNITS						
I _{T(AV)}	Sinusoidal waveform	16	^						
I _{RMS}		25	- A						
V _{RRM} /V _{DRM}		1600	V						
I _{TSM}		350	Α						
V _T	16 A, T _J = 25 °C	1.25	V						
dV/dt		500	V/µs						
dl/dt		150	A/µs						
T _J		-40 to +125	°C						

VOLTAGE RATINGS			
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{DRM} , MAXIMUM PEAK DIRECT VOLTAGE V	I _{RRM} /I _{DRM} , AT 125 °C mA
VS-25TTS16SPbF	1600	1600	10



ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TES	T CONDITIONS	VAL	UNITS				
PARAMETER	STINIBUL	SYMBOL TEST CONDITIONS		TYP.	UNITS				
Maximum average on-state current	I _{T(AV)}	T _C = 93 °C, 180° c	onduction half sine wave	1	6				
Maximum RMS on-state current	I _{RMS}			2	:5	Α			
Maximum peak, one-cycle,	I	10 ms sine pulse, r	ated V _{RRM} applied	3	00	Α			
non-repetitive surge current	I _{TSM}	10 ms sine pulse, r	no voltage reapplied	3	50				
Maximum I ² t for fusing	I ² t	10 ms sine pulse, r	ated V _{RRM} applied	4:	50	A ² s			
Wiaximum i-t for fusing	I-I	10 ms sine pulse, no voltage reapplied			30	A-S			
Maximum I ² √t for fusing	I ² √t	t = 0.1 ms to 10 ms	s, no voltage reapplied	6300		A²√s			
Maximum on-state voltage drop	V_{TM}	16 A, T _J = 25 °C	1.25		V				
On-state slope resistance	r _t	r _t T 105 °C		12	2.0	mΩ			
Threshold voltage	V _{T(TO)}	$T_{\rm J} = 125 ^{\circ}{\rm C}$.0	V				
Maximum reverse and direct leakage current		T _J = 25 °C	V = rotad V = A/	0	.5				
Maximum reverse and direct leakage current	I _{RM} /I _{DM}	T _J = 125 °C	V _R = rated V _{RRM} /V _{DRM}	10					
Holding current	I _H	Anode supply = 6 V, resistive load, initial I_T = 1 A, T_J = 25 °C		1	150	mA			
Maximum latching current	ΙL	Anode supply = 6 V, resistive load, T _J = 25 °C			I _L Anode supply = 6 V, resistive load, T _J = 25 °C 200		00		
Maximum rate of rise of off-state voltage	dV/dt	$T_J = T_J$ max., linear to 80 %, $V_{DRM} = R_g - k = open$		5	00	V/µs			
Maximum rate of rise of turned-on current	dl/dt			15		A/µs			

TRIGGERING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum peak gate power	P _{GM}		8.0	W	
Maximum average gate power	P _{G(AV)}		2.0	VV	
Maximum peak positive gate current	+ I _{GM}		1.5	Α	
Maximum peak negative gate voltage	- V _{GM}		10	V	
		Anode supply = 6 V, resistive load, T _J = - 10 °C	60		
Maximum required DC gate current to trigger	I _{GT}	Anode supply = 6 V, resistive load, $T_J = 25$ °C	45	mA	
		Anode supply = 6 V, resistive load, T_J = 125 °C	20		
		Anode supply = 6 V, resistive load, $T_J = -10 ^{\circ}\text{C}$	2.5		
Maximum required DC gate voltage to trigger	V_{GT}	Anode supply = 6 V, resistive load, T _J = 25 °C 2.0		V	
		Anode supply = 6 V, resistive load, T _J = 125 °C	1.0	V	
Maximum DC gate voltage not to trigger	V_{GD}	T = 105 °C V = Beted value	0.25		
Maximum DC gate current not to trigger	I _{GD}	T _J = 125 °C, V _{DRM} = Rated value	2.0	mA	

SWITCHING								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Typical turn-on time	t _{gt}	T _J = 25 °C	0.9					
Typical reverse recovery time	t _{rr}	T _{.1} = 125 °C	4	μs				
Typical turn-off time	t _q	1j = 125 C	110					



THERMAL AND MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range	T _J , T _{Stg}		-40 to +125	°C				
Soldering temperature	Ts	For 10 s (1.6 mm from case)	260					
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	1.1	°C/W				
Typical thermal resistance, junction to ambient (PCB mount)	R _{thJA} ⁽¹⁾		40	C/VV				
Approximate weight			2	g				
Approximate weight			0.07	OZ.				
Marking device		Case style D ² PAK (TO-263AB)	25TT	S16S				

Note

⁽¹⁾ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 µm] copper 40 °C/W; for recommended footprint and soldering techniques refer to application note #AN-994

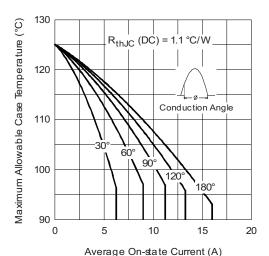


Fig. 1 - Current Rating Characteristics

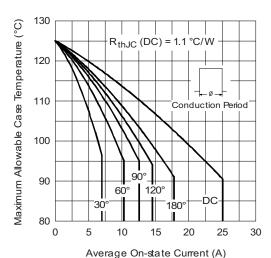


Fig. 2 - Current Rating Characteristics

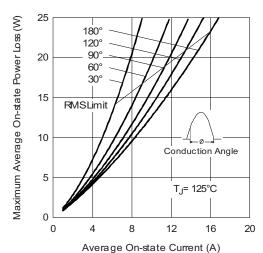


Fig. 3 - On-State Power Loss Characteristics

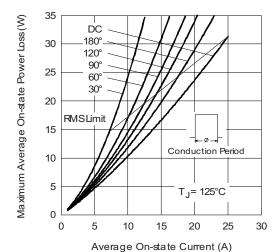


Fig. 4 - On-State Power Loss Characteristics



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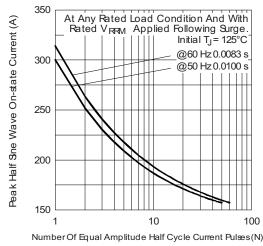


Fig. 5 - Maximum Non-Repetitive Surge Current

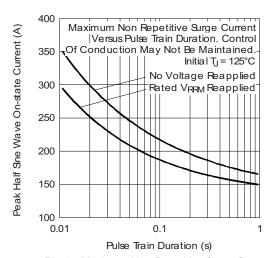


Fig. 6 - Maximum Non-Repetitive Surge Current

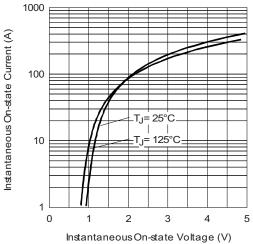
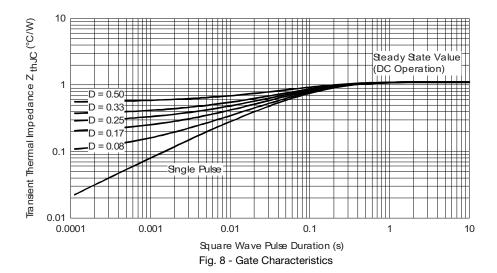


Fig. 7 - On-State Voltage Drop Characteristics



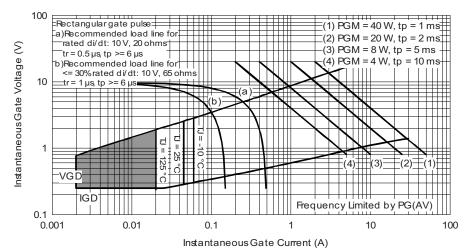


Fig. 9 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Danisha		0.5		_		40			
Device code	VS-	25	Т	T	S	16	S	TRL	PbF
	1	2	3	4	5	6	7	8	9
	1 .	Visl	nay Sen	niconduc	ctors pro	oduct			
	2 -	- Current rating (25 = 25 A)							
	3 -		Circuit configuration:						
	4	Pac	single t kage: TO-220						
	5	٠.	e of silic		am, raat	ifiar			
	6			rd recoving: volta	•		= V _{RRN}	1	16 = 1
	7	S =	$S = TO-220 D^2PAK (TO-263AB) version$						
	8 -	• TF	•	be e and re be and re	`		,		
	9 -	PbF	= lead	(Pb)-fre	е				

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-25TTS16SPbF	50	1000	Antistatic plastic tubes						
VS-25TTS16STRRPbF	800	800	13" diameter reel						
VS-25TTS16STRLPbF	800	800	13" diameter reel						

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95046					
Part marking information	www.vishay.com/doc?95054					
Packaging information	www.vishay.com/doc?95032					

Revision: 10-Aug-2018 5 Document Number: 94679



D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INC	INCHES		NOTES	SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOIES		STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	2.54 BSC 0.100 BSC			
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	.3 0.25 BSC 0.010 BSC				
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB

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